



High Voltage Single SPDT Analog Switch in SOT23-8

DESCRIPTION

The DG449 is a dual supply single-pole/double-throw (SPDT) switches. On resistance is 38Ω and flatness is 2.6Ω max over the specified analog signal range. These analog switches were designed to provide high speed, low error switching of precision analog signals. The primary application areas are in the routing and switching in telecommunications and test equipment. Combining low power, low leakages, low on-resistance and small physical size, the DG449 is also ideally suited for portable and battery powered industrial and military equipment.

The DG449 operates either from a single $+7\text{ V}$ to 36 V supply or from dual $\pm 4.5\text{ V}$ to $\pm 20\text{ V}$ supplies. It is offered in the very popular, small SOT23-8 package.

FEATURES

- $\pm 15\text{ V}$ Analog Signal Range
- On-Resistance - $r_{DS(on)}$: 38Ω max
- V_L Logic Supply Not Required
- TTL CMOS Input Compatible
- Rail To Rail Signal Handling
- Dual Or Single Supply Operation



RoHS
COMPLIANT

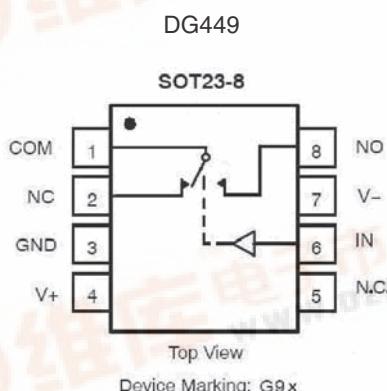
BENEFITS

- Wide Dynamic Range
- Low Signal Errors and Distortion
- Break-Before-Make Switching Action
- Simple Interfacing
- Small SOT23-8d package; Reduced Board Space
- Improved Reliability

APPLICATIONS

- Precision Test Equipment
- Precision Instrumentation
- Communications Systems
- PBX, PABX Systems
- Audio Equipment
- Redundant Systems
- PC Multimedia Boards
- Hard Disc Drives

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE

Logic	NC	NO
0	ON	OFF
1	OFF	ON

Logic "0" $\leq 0.8\text{ V}$

Logic "1" $\geq 2.4\text{ V}$

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ORDERING INFORMATION

Temp Range	Package	Part Number
- 40 to 85 °C	8-Pin SOT23	DG449DS-T1-E3

ABSOLUTE MAXIMUM RATINGS $T_A = 25^\circ\text{C}$, unless otherwise noted

Parameter (Voltages Referenced to V-)	Symbol	Limit	Unit
V+		44	V
GND		25	
Digital Inputs ^a , $V_{no/nc}$, V_{COM}		(V-) - 2 V to (V+) + 2 V or 30 mA, whichever occurs first	
Current, (Any Terminal) Continuous		30	mA
Current (NO, NC or COM) Pulsed at 1 ms, 10 % duty cycle		100	
Storage Temperature		- 65 to 150	°C
Power Dissipation (Package) ^b	8-Pin SOT-23 ^c	675	mW

Notes:

- a. Signals on NO, NC, COM, or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 8.4 mW/°C above 70 °C.



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SPECIFICATIONS ^a							
Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 15 \text{ V}$, $V_- = -15 \text{ V}$ $V_{IN} = 2.4 \text{ V}$, 0.8 V^f	Temp ^b	D Suffix -40 to 85 °C			Unit
				Min ^d	Typ ^c	Max ^d	
Analog Switch							
Analog Signal Range ^e	V_{ANALOG}			Full	-15	15	V
On-Resistance	r_{ON}	$I_{no/nc} = 1 \text{ mA}$, $V_{COM} = \pm 8.5 \text{ V}$ $V_+ = 13.5 \text{ V}$, $V_- = -13.5 \text{ V}$	Room		38	45	Ω
On Resistance MATCH	Δr_{ON}		Full		5	6	
On-Resistance Flatness	r_{ON} Flatness	$I_{no/nc} = 1 \text{ mA}$, $V_{COM} = \pm 5 \text{ V}$, 0 V $V_+ = 13.5 \text{ V}$, $V_- = -13.5 \text{ V}$	Room		2.6	7	nA
Switch Off Leakage Current	$I_{no/nc(off)}$	$V_+ = 16.5 \text{ V}$, $V_- = -16.5 \text{ V}$ $V_{COM} = \pm 15.5 \text{ V}$ $V_{no/nc} = -/+ 15.5 \text{ V}$	Room	-1	-0.1	1	
	$I_{COM(off)}$		Full	-10	-0.1	10	
Channel On Leakage Current	$I_{COM(on)}$	$V_+ = 16.5 \text{ V}$, $V_- = -16.5 \text{ V}$ $V_{COM} = V_{no/nc} = \pm 15.5 \text{ V}$	Room	-2	-0.1	2	μA
Digital Control							
Input, High Voltage	I_{INH}		Full	2.4			V
Input, Low Voltage	I_{INL}		Full			0.8	
Input Capacitance ^e	C_{IN}		Room		4		pF
Input Current V_{IN} High or Low	I_{IN}	$V_{IN} = 0$ or 5 V		-1		1	μA
Dynamic Characteristics							
Turn-On Time	t_{ON}	$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$ $V_{no/nc} = \pm 10 \text{ V}$	Room		107	146	ns
Turn-Off Time	t_{OFF}		Full		69	104	
Charge Injection ^e	Q	$C_L = 1 \text{ nF}$, $V_{gen} = 0 \text{ V}$, $R_{gen} = 0 \Omega$	Room		5		pC
Off-Isolation ^e	OIRR	$R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 1 \text{ MHz}$	Room		-69		dB
Crosstalk ^e	X_{TALK}	$R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 1 \text{ MHz}$			-80		
Source NO, NC Off Capacitance ^e	$C_{no/nc(off)}$	$f = 1 \text{ MHz}$	Room		8		pF
Channel On Capacitance ^e	$C_{COM(on)}$	$f = 1 \text{ MHz}$	Room		18		
Power Supplies							
Positive Supply Current	I_+	$V_+ = 16.5 \text{ V}$, $V_- = -16.5 \text{ V}$ $V_{IN} = 0$, 5 V or, V_+	Room		4	20	μA
Negative Supply Current	I_-		Full	-1	-3		

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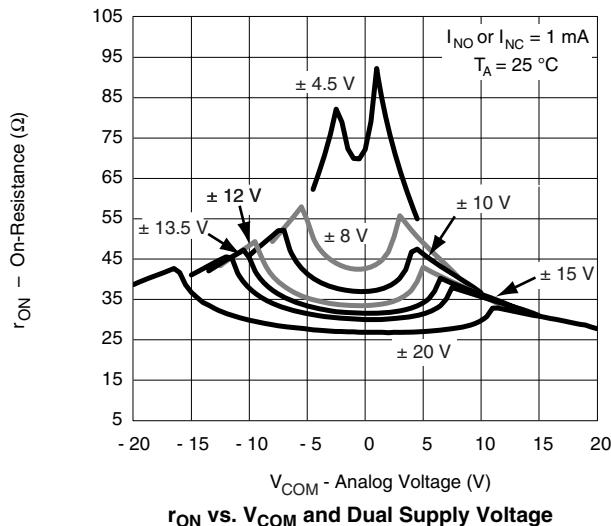
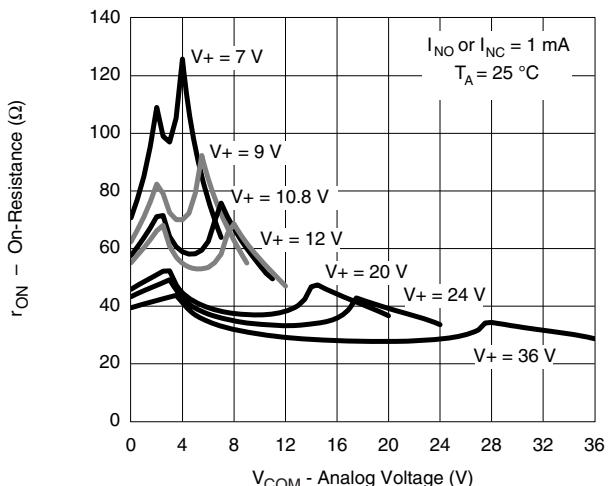
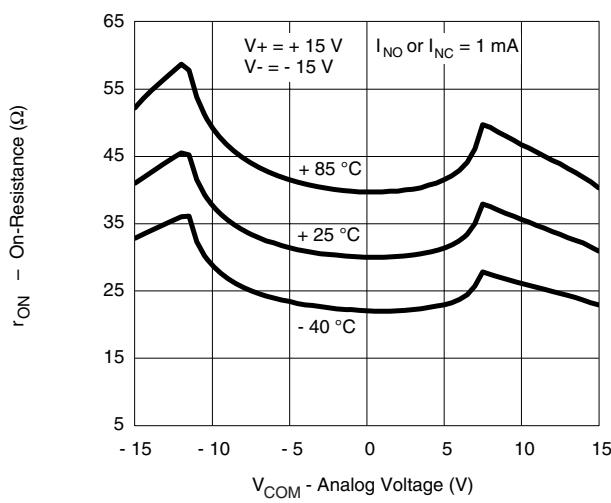
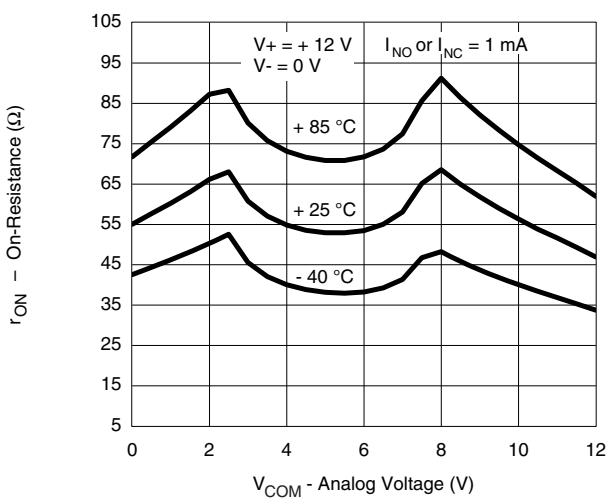
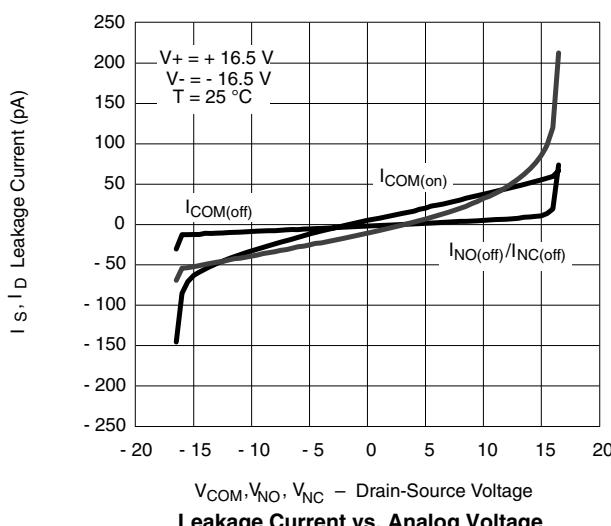
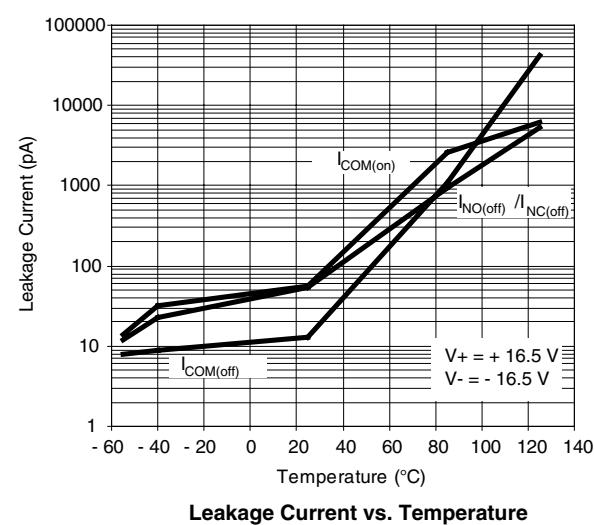
SPECIFICATIONS^a

Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 12 \text{ V}$, $V_- = 0 \text{ V}$ $V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^f$	Temp ^b	D Suffix - 40 to 85 °C			Unit
				Min ^d	Typ ^c	Max ^d	
Analog Switch							
Analog Signal Range ^e	V_{ANALOG}		Full	0		12	V
On-Resistance	r_{ON}	$I_{no/nc} = 1 \text{ mA}$, $V_{COM} = 3, 8 \text{ V}$ $V_+ = 10.8 \text{ V}$	Room		67	85	Ω
On-Resistance MATCH	Δr_{ON}		Full			4	
On-Resistance Flatness	r_{ON} Flatness	$I_{no/nc} = 1 \text{ mA}$, $V_{COM} = 2, 6, 10 \text{ V}$ $V_+ = 10.8 \text{ V}$	Room		17	25	
Dynamic Characteristics							
Turn-On Time	t_{ON}	$V_{NO, NC} = 10 \text{ V}$, $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$	Room		133	168	nS
Turn-Off Time	t_{OFF}		Full		58	92	
Charge Injection ^e	Q	$C_L = 1 \text{ nF}$, $V_{gen} = 0 \text{ V}$, $R_{gen} = 0 \Omega$	Room		6		pC
Power Supplies							
Positive Supply Current	I_+	$V_+ = 13.2 \text{ V}$, $V_{IN} = 0 \text{ V}, 5 \text{ V}$ or V_+	Room		3	20	μA

Notes:

- a. Refer to PROCESS OPTION FLOWCHART .
- b. Room = 25 °C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

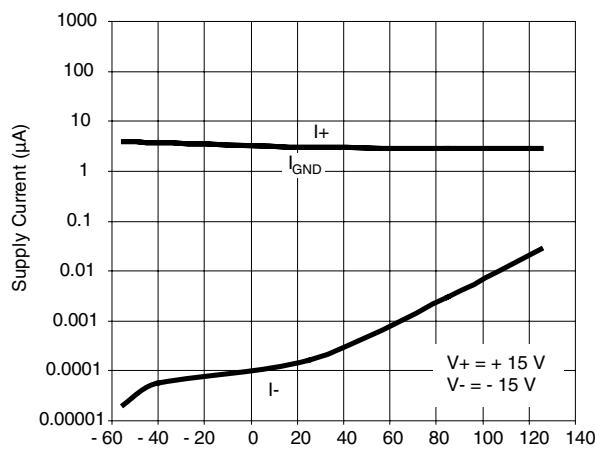
TYPICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, unless otherwise noted

 r_{ON} vs. V_{COM} and Dual Supply Voltage

On Resistance vs. V_{COM} and Single Supply Voltage

On Resistance vs. V_{COM} and Temperature

On Resistance vs. V_{COM} and Temperature

Leakage Current vs. Analog Voltage

Leakage Current vs. Temperature

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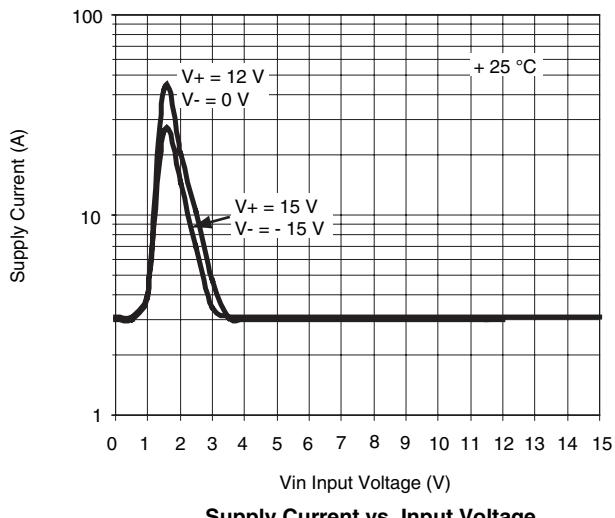
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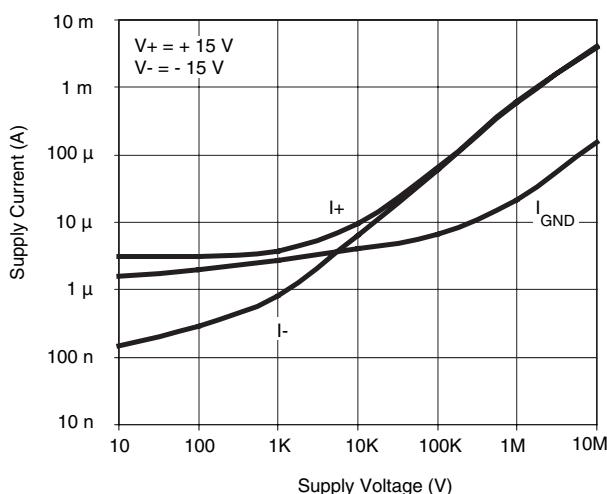
TYPICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, unless otherwise noted



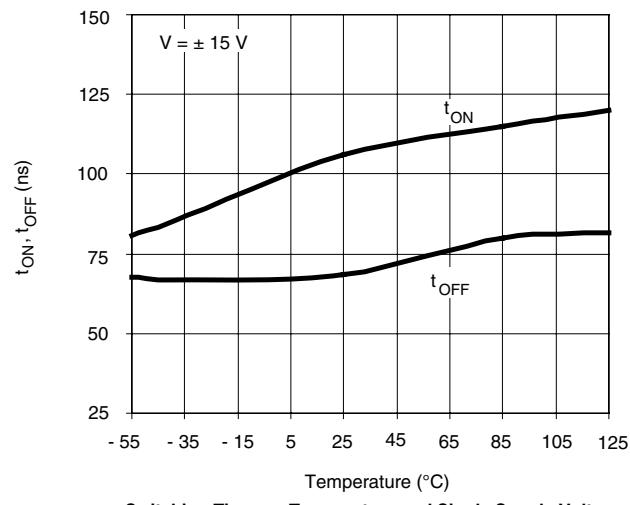
Supply Current vs. Temperature



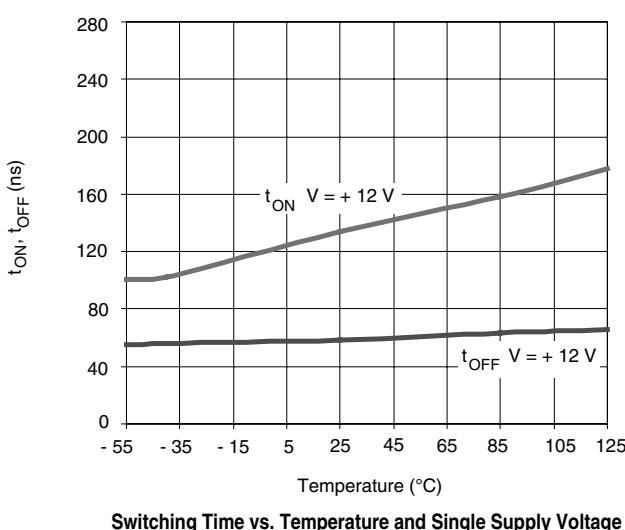
Supply Current vs. Input Voltage



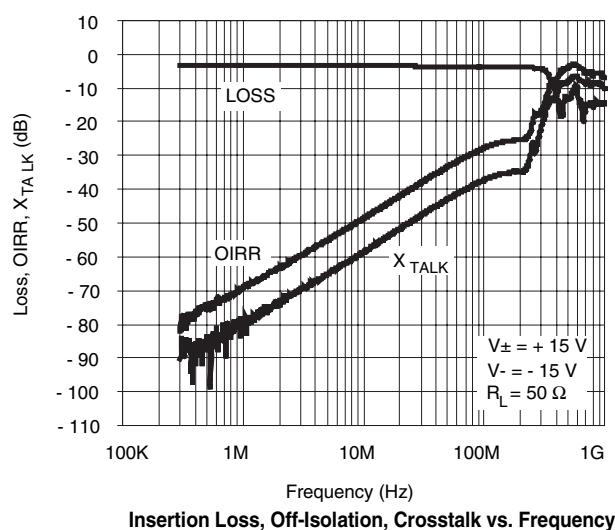
Supply Current vs. Input Switching Frequency



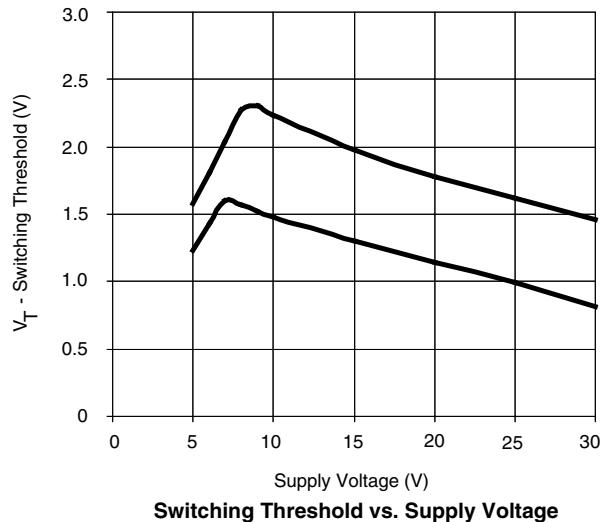
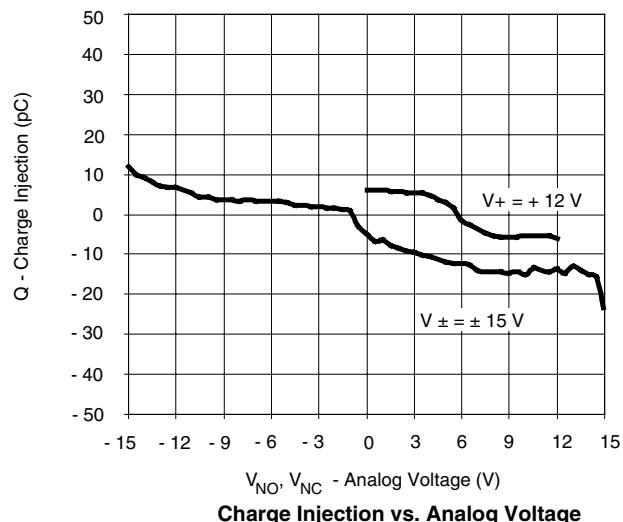
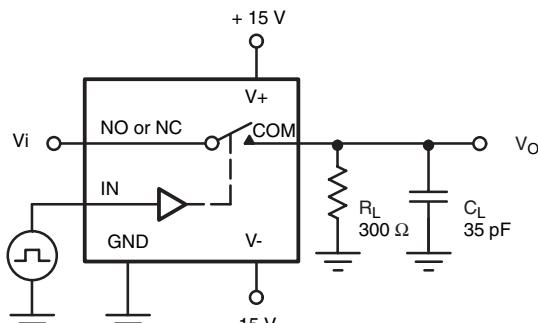
Switching Time vs. Temperature and Single Supply Voltage



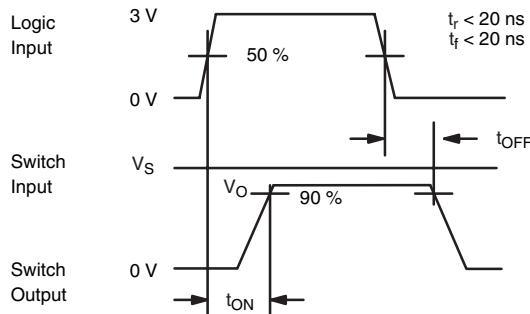
Switching Time vs. Temperature and Single Supply Voltage



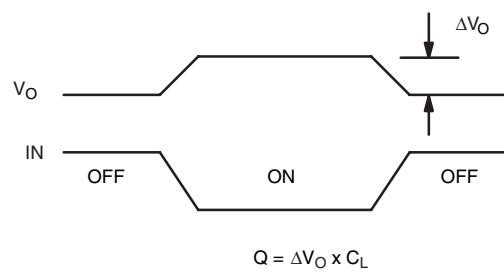
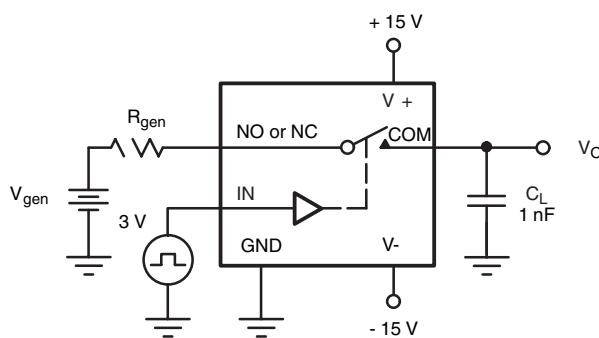
Insertion Loss, Off-Isolation, Crosstalk vs. Frequency

TYPICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, unless otherwise noted

Switching Threshold vs. Supply Voltage

Charge Injection vs. Analog Voltage
TEST CIRCUITS
 V_O is the steady state output with the switch on.

 C_L (includes fixture and stray capacitance)

$$V_O = V_i \cdot \frac{R_L}{R_L + r_{ON}}$$

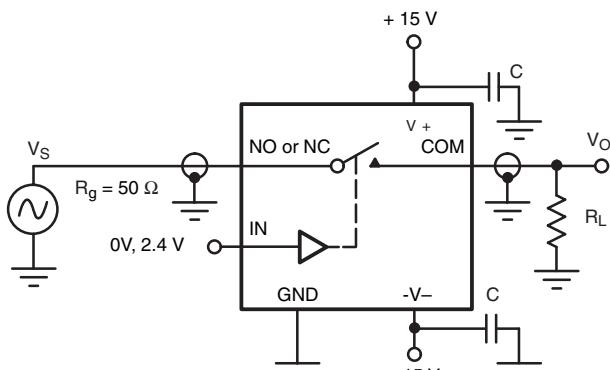


Note: Logic input waveform is inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

Figure 2. Charge Injection

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$$\text{Off Isolation} = 20 \log \frac{V_{COM}}{V_{NO/NC}}$$

Figure 3. Off Isolation

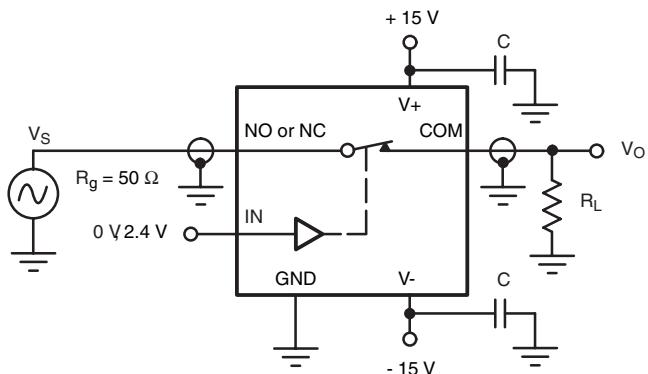


Figure 4. Insertion Loss

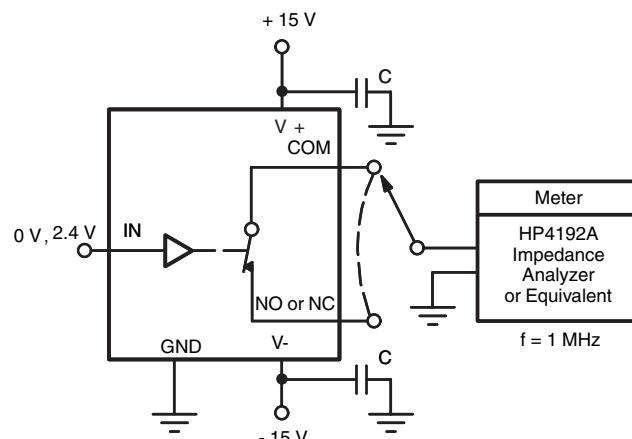


Figure 5. Channel ON/OFF Capacitances

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